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**Role of Binder in Sol-gel Synthesis of Ta<sub>2</sub>O<sub>5</sub> Films for Photonic Crystal Fabrication**

**By**

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## **Abstract**

Advances in microelectromechanical systems has generated an ever growing demand for novel insulating material applicable to high temperature systems. Photonic bandgap materials are appealing for such applications, specifically Ta<sub>2</sub>O<sub>5</sub> due to its high index of refraction, refractory nature and negligible absorbance in the infrared region. The challenge faced in the realization of such materials is the synthesis of Ta<sub>2</sub>O<sub>5</sub> films whose thickness is in the order of a quarter wavelength of the incident **infrared**.

This work seeks to investigate the effect of addition of polyvinyl pyrrolidone (PVP) binder material in the sol gel synthesis of thick, uniform and crack free Ta<sub>2</sub>O<sub>5</sub> films. Incorporation of PVP into the sol precursor has enabled uniform and crack free films with thicknesses of up to 1.6 microns to be realized. Chemical probing of the precursor was conducted via TGA, FTIR, and NMR analysis of the sol to elucidate the processes behind this film formation. The calcined oxide films were characterized via SEM, XRD and XPS.

**Keywords:** Ta<sub>2</sub>O<sub>5</sub> film, PVP, sol gel, thick films, photonic bandgap, photonic crystals

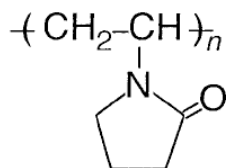
## **Introduction**

Insulation for high temperature microelectromechanical systems has become a key area in research due to the development of microreactor systems that can attain wall temperatures in the order of 1200°C.<sup>1,2</sup> In order to add utility and portability to such systems it is required to thermally isolate parts of composite devices that incorporate such high temperature components. Thick refractory blocks (e.g. fibrous alumina) are the best mode of insulation currently available.

However, multilayer quarterwave photonic crystals have shown a tunability such as to exhibit a photonic bandgap in the infrared wavelength.<sup>3</sup> This is promising since at temperatures above 600°C, IR radiation is the dominant mode of heat loss,<sup>4,5</sup> thus a multitude of structures can be explored to insulate or anisotropically expel heat generated by microreactors.

The greatest challenge posed in realizing such materials is that photonic crystals with a bandgap in the IR calls for structures made out of dense refractory material with

thicknesses ranging from 1-5  $\mu\text{m}$ .<sup>3</sup>  $\text{Ta}_2\text{O}_5$  is the material of choice due to its high index of refraction, refractory nature and negligible absorbance in the infrared region.<sup>4, 6, 7</sup> Current deposition techniques typically attain thicknesses in the order of 1-1.5  $\mu\text{m}$ .<sup>7-14</sup> Furthermore, these are achieved by use of high cost systems such as chemical vapour deposition, e-beam deposition etc. Any attempts at thicknesses beyond this range are hampered by slow growth rates and film cracking and delamination.<sup>9, 15, 16</sup> Solgel synthesis techniques are appealing due to their low cost and flexibility with regards to chemical tuning of the properties of the final material sought. Binder molecules such as ethylcellulose, polyethyleneimine (PEI), polyvinyl pyrrolidone (PVP) and polyvinyl butyral (PVB) have been shown to increase film thickness with little or no cracking when incorporated in the sol precursor.<sup>17-22</sup> Previous studies have shown PVP to yield dense and thick  $\text{Ta}_2\text{O}_5$  films on silicon with minimal or no cracking.<sup>23</sup> These films retained their stability even after prolonged heating at high temperature. **Despite these discoveries, the mechanisms via which PVP facilitates the superior quality of oxide films still remains to be understood, hence** in this paper, we seek to investigate the precise effect of the PVP binder molecule in the preparation of thick  $\text{Ta}_2\text{O}_5$  films. The sol precursors were analyzed with time from the point of synthesis till 12 days later. Chemical probing was done via FTIR and NMR analysis. Thermogravimetric analysis (TGA) of the sol precursor was also performed. The resulting oxide films were characterized via scanning electron microscopy (SEM), X-Ray diffraction (XRD) and X-Ray Photoelectron Spectroscopy (XPS). The binder was found to have a viscosity increasing effect when incorporated into the sol precursor. This allowed for thicker films due to the increased surface tension during spin or dip coating. PVP also reduces the rate of solvent expulsion from the wet film and has been suggested to facilitate hydrogen bond formation within the film matrix, which limits crack formation during drying and high temperature sintering.<sup>18, 24</sup>



PVP

## Experimental Section

**Sol synthesis:** 1-propanol (Aldrich<sup>®</sup> CAS# 71-23-8) was added to tantalum (V) ethoxide (Aldrich<sup>®</sup> CAS# 6074-84-6) in a 100ml round bottomed flask while stirring to prevent rapid hydrolysis of the latter when exposed to ambient moisture. PVP (Aldrich<sup>®</sup> CAS# 9003-39-8) (avg mw 1, 000, 000) was weighed out and 2-methoxyethanol (Aldrich<sup>®</sup> CAS# 109-86-4) added to it while stirring (molecular weight of PVP monomer was used in the calculations). The mixture was further sonicated for 15 minutes to achieve complete binder dissolution. The PVP & 2-methoxyethanol solution was then added to the tantalum(V)ethoxide & 1-propanol solution while stirring. The resulting mixture was then refluxed for 2 hours at 130°C. This was followed by vacuum evaporation until a 12% loss in mass was attained. The solution was then let to cool to room temperature, after which acetylacetone (Aldrich<sup>®</sup> CAS# 123-54-6) was added yielding a deep yellow colored solution. The solution was let to stir for 20 hrs in a capped flask. This resulting sol was used for deposition by spin coating at various age points. Further details are discussed elsewhere.<sup>23</sup> The films were then left to dry in air for 24 hrs then subjected to a 9hr bake at 1000°C under an O<sub>2</sub> flow of 100 cm<sup>3</sup>/min. Temperature ramping rate was 1.6°C/min for both up and down cycles. (fig. 1)

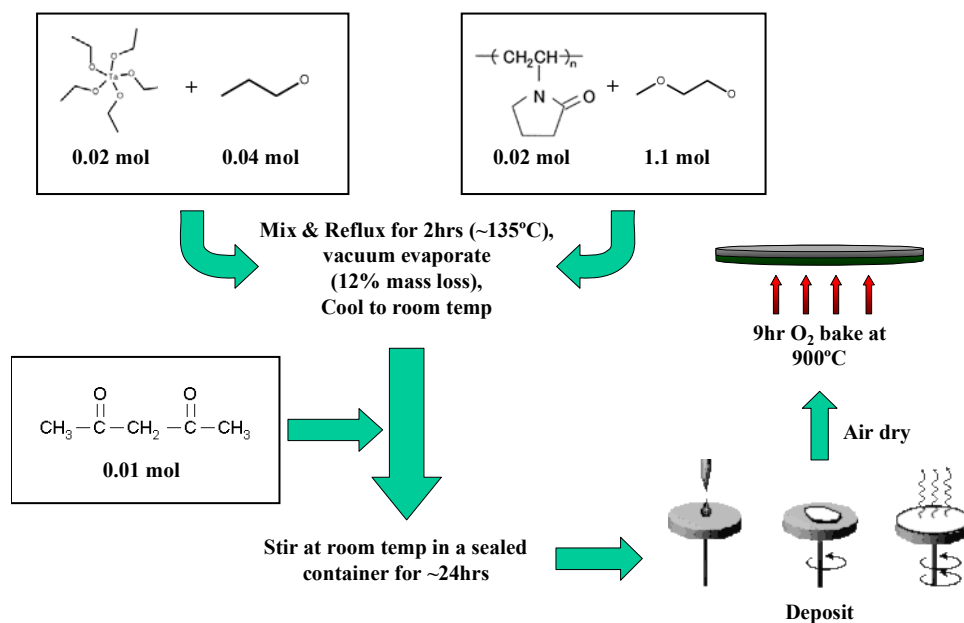


Figure 1: Sol gel scheme of synthesis & deposition of Ta<sub>2</sub>O<sub>5</sub>

Two control samples were synthesized; the first **without** PVP, and the second **without** acetylacetone.

## **Results**

**FTIR analysis:** Given the strong positively charged **Ta** metal center bonded to negatively charged ligands, the large dipole moment typically yields characteristically strong IR bands for metallorganic compounds. Infra red analysis also reveals the presence of hydrogen bonds.<sup>25, 26</sup> Sampling for FTIR was in the form of dip coated liquid films on a silicon substrate, analyzed on a Magna IR Spectrometer 750<sup>®</sup> from Nicolet Instrument Corp. FTIR in the reflectance mode at 45° incidence angle. FTIR sampling of the sol and control sol (without acetylacetone) was conducted periodically starting at the end of sol synthesis, till the 12<sup>th</sup> day. (fig. 5 & 6). Spectra of the solvent (fig. 2) and PVP in 2-methoxyethanol solution (fig. 3) were also collected. Samples were Si <111> substrates (acetone-isopropanol rinsed) hand dipped in the respective sample at the indicated points in time.

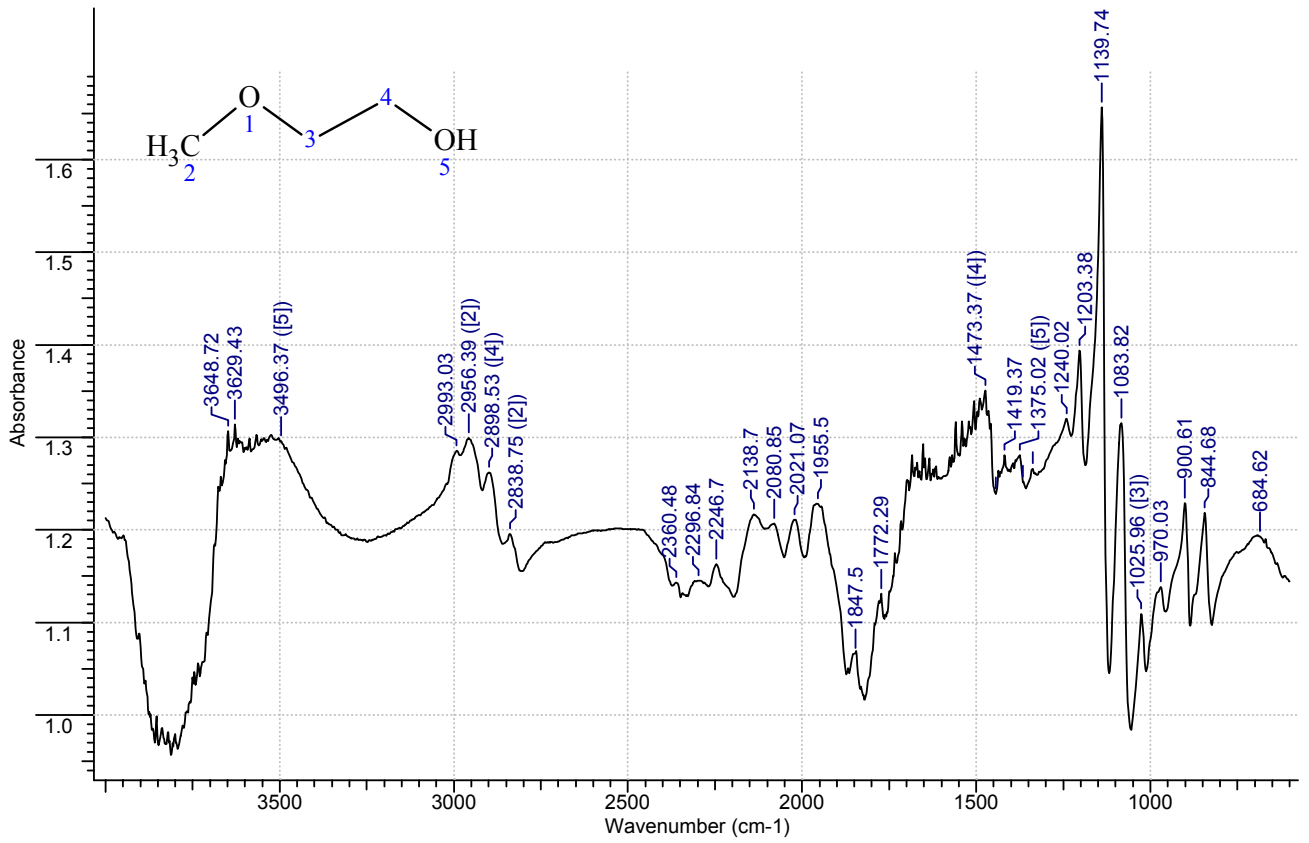


Figure 2: FTIR spectrum of 2-methoxyethanol film on Si<111>

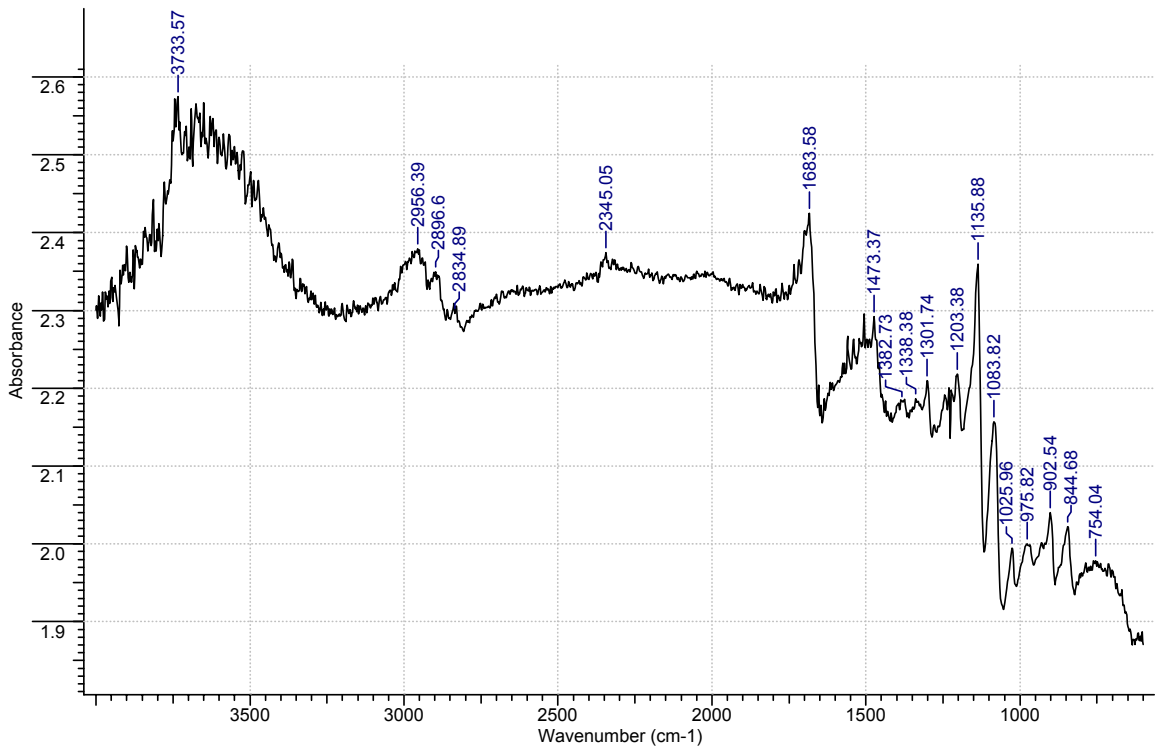


Figure 3 FTIR spectrum of PVP in 2-methoxyethanol film on Si<111>

cm <sup>-1</sup>	Vibr/trans	ref
1025.96	CH <sub>2</sub> undefined	25, 26
1338.38	H-O in-plane bending	25-27
1375.02	H-O in-plane bending	25-27
1444.44	CH <sub>3</sub> umbrella mode	25, 26
1473.37	CH <sub>2</sub> scissoring	25, 26
2838.75	CH <sub>2</sub> sym stretching	25, 26
2898.53	CH <sub>2</sub> sym stretching	25, 26
2956.39	CH <sub>3</sub> asym stretching	25, 26
3496.37	O-H stretching	22, 25-28
1139.74	Si-O stretch	25, 26
1083	Si-O stretch	8, 25, 26
2080-2250	Si-H stretching	25, 26
1640-1690	C=O stretching	22, 25, 26, 28
1297	C-N stretch	22, 25, 26, 28
1383	C-H bending	22, 26, 28
1099-1053	Ta-O-C	8, 27, 29
<1000	(Ta-O) stretch, bend and torsion modes	8, 27, 29

Figure 4: FTIR table of assignments

### Analysis of sol with acetylacetone:

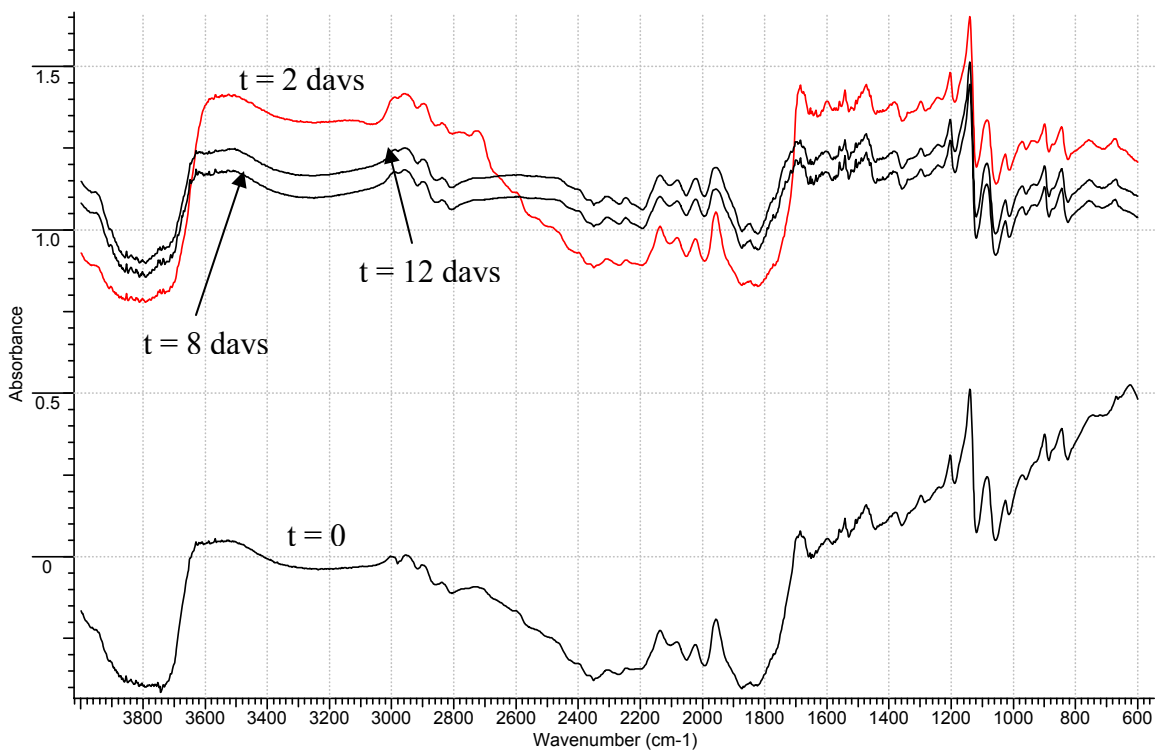


Figure 5: FTIR spectra of sol containing acetylacetone

Spectrum is identical to that of 2-methoxyethanol (fig. 2) except for C=O stretch at  $1700\text{cm}^{-1}$ ,  $1297\text{cm}^{-1}$  C-N stretch and two bands at  $650\text{cm}^{-1}$  and  $770\text{cm}^{-1}$  attributable to Ta-O or Ta-O-C modes<sup>27, 29</sup>. The spectra obtained do not show any noticeable change with time.  $^{13}\text{C}$  and  $^1\text{H}$  NMR spectra show no change with time either.

#### Analysis of sol without acetylacetone:

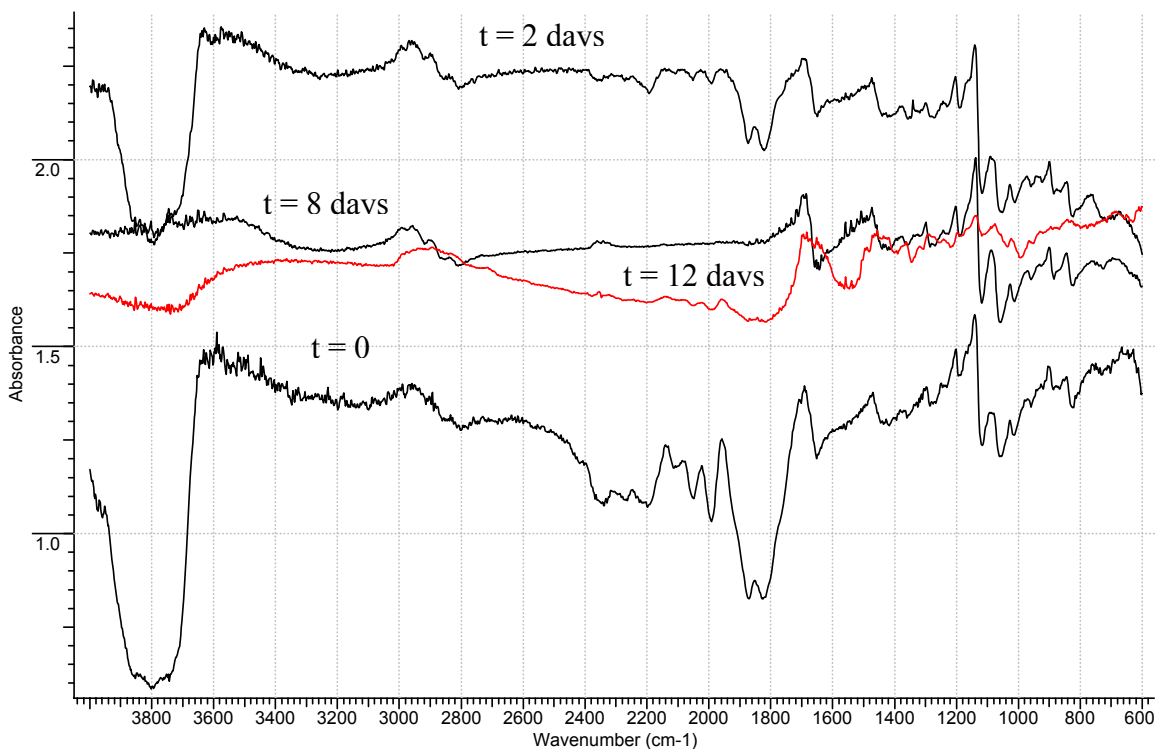


Figure 6: FTIR spectra of control sol (no acetylacetone)

Initially identical to 2-methoxyethanol (fig. 2) except for  $1297\text{cm}^{-1}$  C-N and  $1690\text{cm}^{-1}$  C=O stretch modes. With time, OH and methoxy  $\text{CH}_2$  &  $\text{CH}_3$  bands broaden out, leaving only the  $1297\text{cm}^{-1}$  C-N,  $1472\text{cm}^{-1}$   $\text{CH}_2$  scissoring,  $1690\text{cm}^{-1}$  C=O and  $1140\text{cm}^{-1}$  Si-O bands distinctly visible.<sup>25, 26</sup> Two bands at  $650\text{cm}^{-1}$  and  $770\text{cm}^{-1}$  attributable to Ta-O or Ta-O-C modes are present but broad and not as distinct as observed for the sol precursor.<sup>27, 29</sup> The broad OH band at  $\sim 3600$  diminishes in relative intensity with time. The sol visibly turns turbid with time.  $^{13}\text{C}$  and  $^1\text{H}$  NMR spectra taken over time do not show any change. The sample had solidified after the 12<sup>th</sup> day.



**NMR analysis:**  $^1\text{H}$  and  $^{13}\text{C}$  NMR analysis was performed using Varian UNITY 400<sup>®</sup> and Varian UNITY 500<sup>®</sup> systems using Wilmad 528-PP-7<sup>®</sup> sample tubes. This analysis was important in determining what ligands are attached to the metal center at the end of the synthesis, as well as the fate of the exchanged hydrocarbon groups.<sup>30, 31</sup> NMR sampling was conducted daily over a period of 3 days starting at the end of sol synthesis, and thereafter every 2 days till the 18<sup>th</sup> day from the end of synthesis. The NMR standard used was duterated chloroform 99.8 atom % D with 1 % (v/v) TMS. The different samples analyzed were:

- Sol synthesized above (fig. 1)
- Sol synthesized as above but without PVP
- All the above but with  $\text{CaSO}_{4(s)}$  pellet acting as  $\text{H}_2\text{O}$  scavenger
- Sol synthesized as above but without acetylacetone

There was no variation in the  $^1\text{H}$  and  $^{13}\text{C}$  spectra obtained from the ageing samples, except for a random shift in the upfield broad band appearing in all the  $^1\text{H}$  spectra of  $\pm 0.5$  ppm (fig. 7 & 8). Spectra obtained from the control samples were similar to the spectra of the actual precursor.

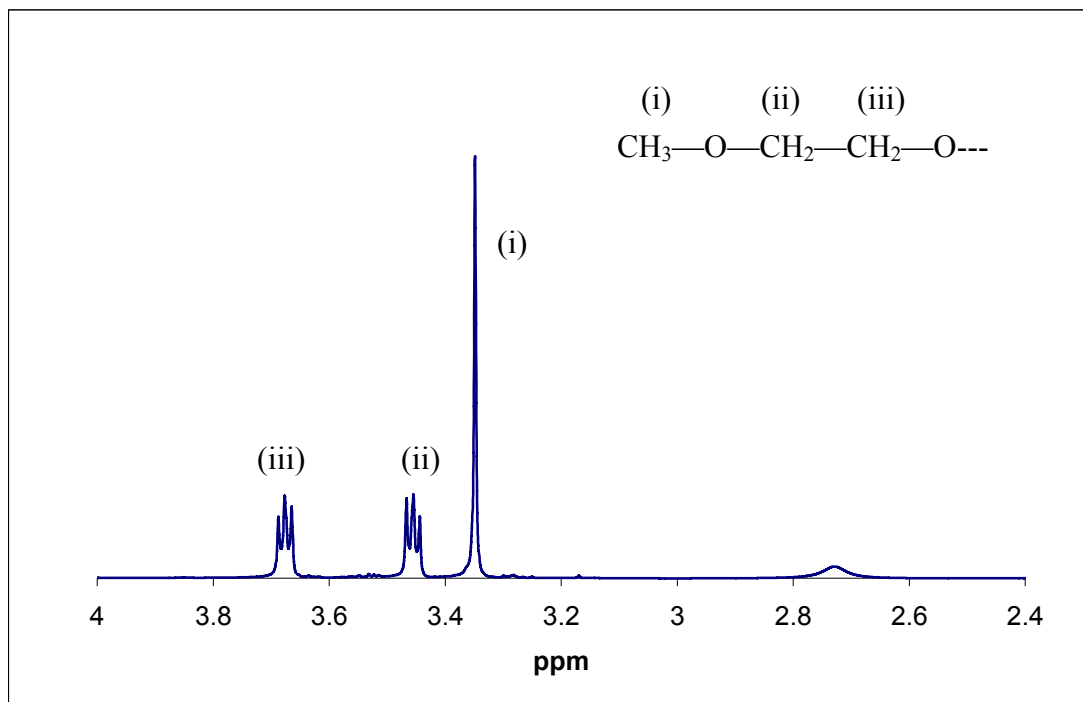


Figure 7:  $^1\text{H}$  NMR of  $\text{Ta}_2\text{O}_5$  precursor (freshly synthesized sol)

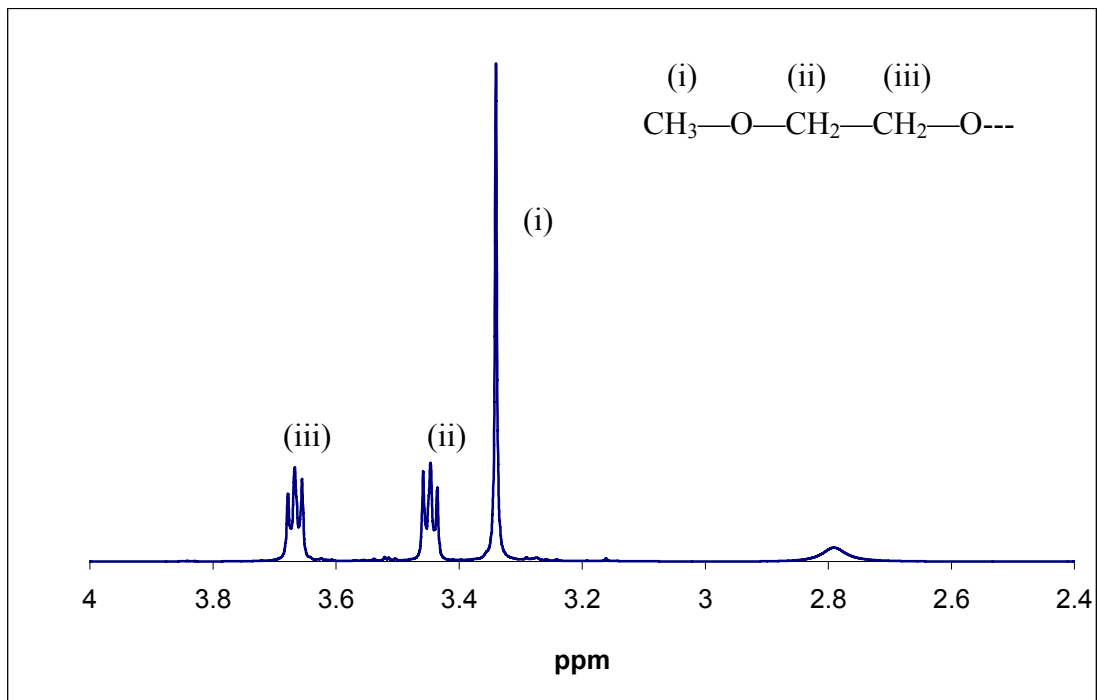


Figure 8:  $^1\text{H}$  NMR of  $\text{Ta}_2\text{O}_5$  precursor (sol is 3 days old)

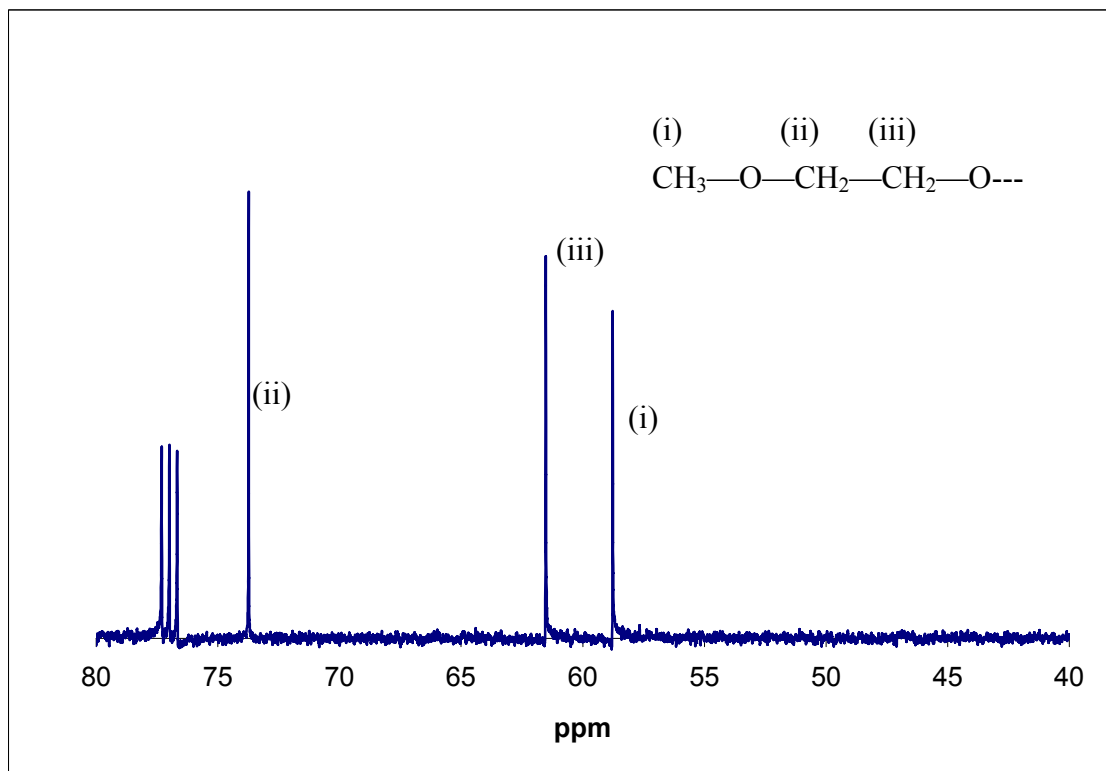
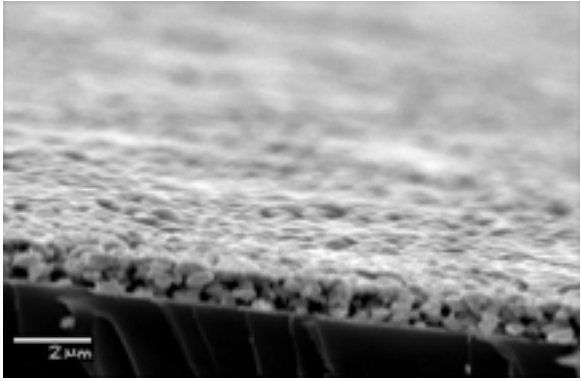
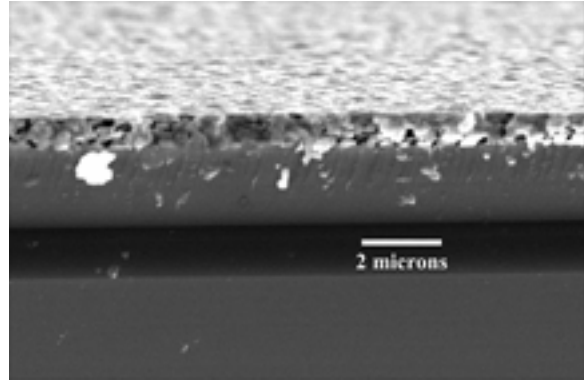


Figure 9:  $^{13}\text{C}$  NMR of  $\text{Ta}_2\text{O}_5$  precursor

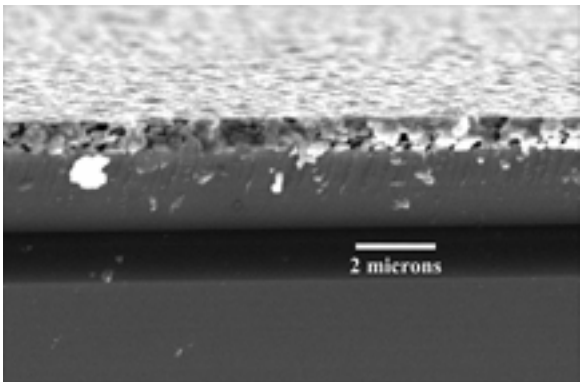
**SEM analysis:** Scanning Electron Microscopy (SEM) was performed on samples of green (uncalcined) films and resulting oxide films to examine the microstructure resulting from the sols of different ages. Analysis was done on JEOL 6060LV<sup>®</sup> SEM machine. (fig 10 & 11)



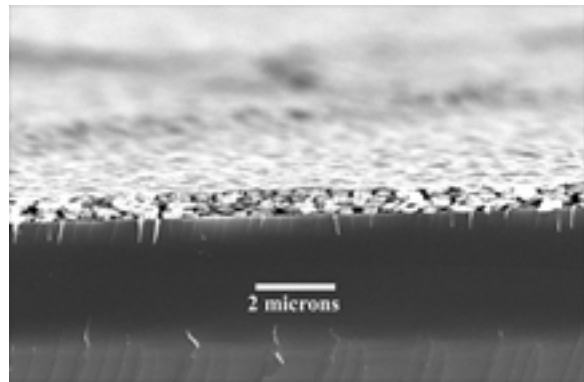
(a) Ta<sub>2</sub>O<sub>5</sub> film deposited on Si at t = 0 hrs



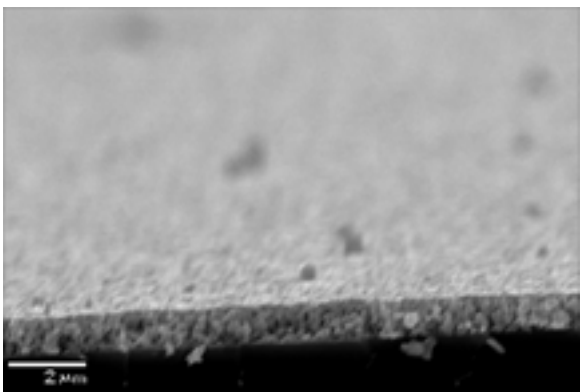
(b) Ta<sub>2</sub>O<sub>5</sub> film deposited on Si at t = 12 hrs



(c) Ta<sub>2</sub>O<sub>5</sub> film deposited on Si at t = 24 hrs

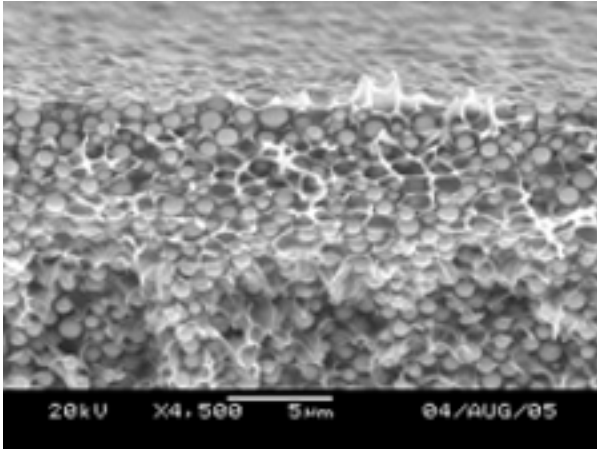


(d) Ta<sub>2</sub>O<sub>5</sub> film deposited on Si at t = 48 hrs

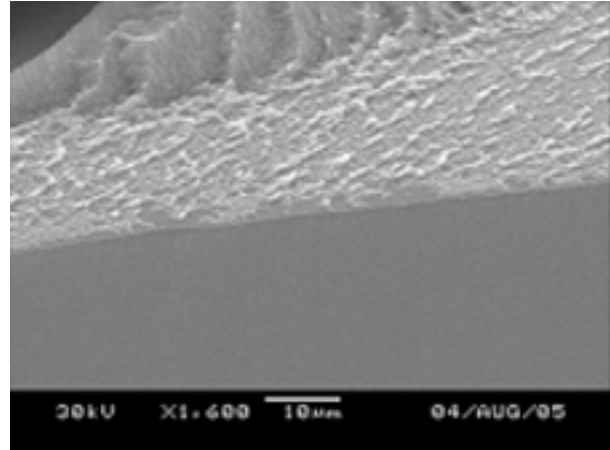


(e) Ta<sub>2</sub>O<sub>5</sub> film deposited on Si at t = 8 days

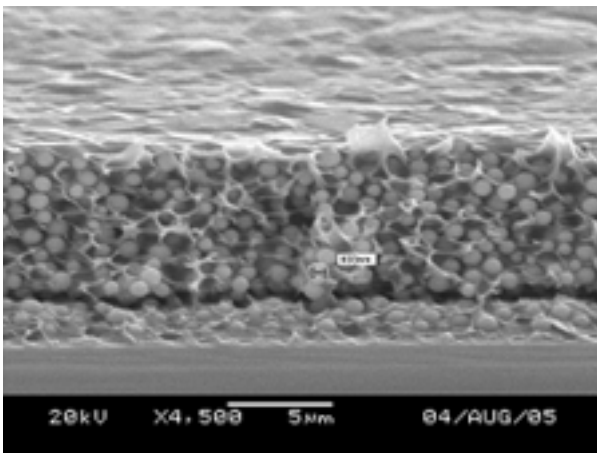
Figure 10: SEM micrographs of calcined Ta<sub>2</sub>O<sub>5</sub> films on Si <100> deposited from sols of varying age



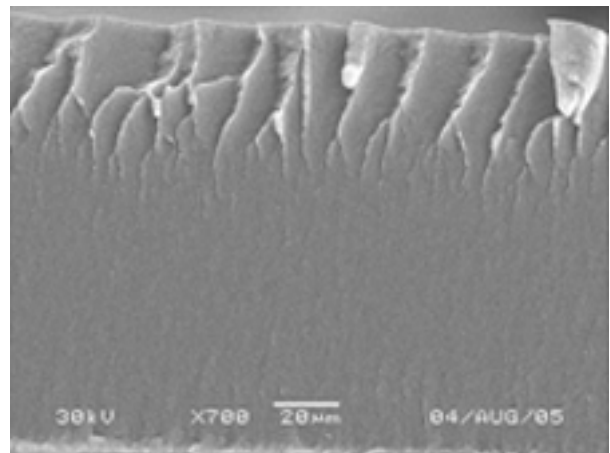
(a) green film from fresh sol with acetylaceton



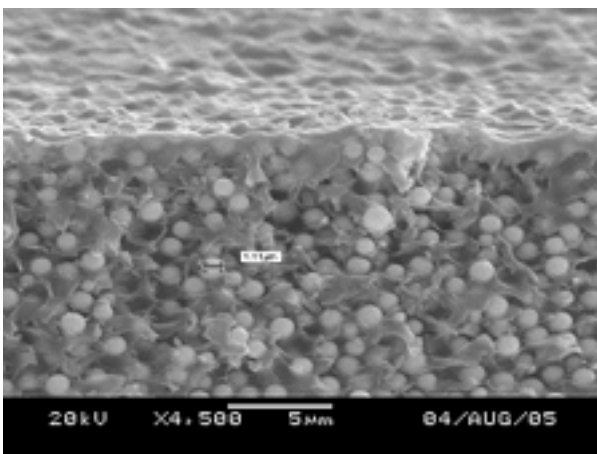
(d) green film from fresh sol without acetylaceton



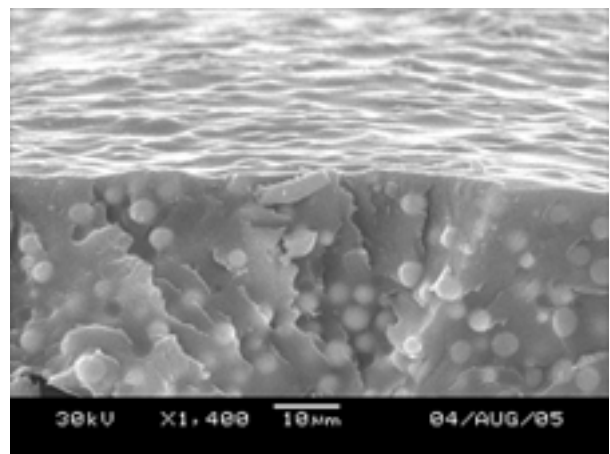
(b) green film from 5 day old sol with acetylaceton



(e) green film from 5 day old sol without acetylaceton



(c) green film from 12 day old sol with acetylaceton



(f) green film from 12 day old sol without acetylaceton

Figure 11: SEM micrographs of green  $Ta_2O_5$  films on Si <111> deposited from sols of varying age [(a),(b),(c): sol with acetylaceton; (d),(e),(f): sol without acetylaceton]

**XPS analysis:** X-ray photoelectron spectroscopy was used to analyze the residual carbon content of the Ta<sub>2</sub>O<sub>5</sub> films after calcination on a PHI 5400<sup>®</sup> XPS system (Mg K $\alpha$  x-ray source). Analysis was done on the oxide upper surface and within the film (surface was sputtered with Argon for 15 minutes). XPS was also used to reveal the Ta:O:C atomic ratio. (fig. 12)

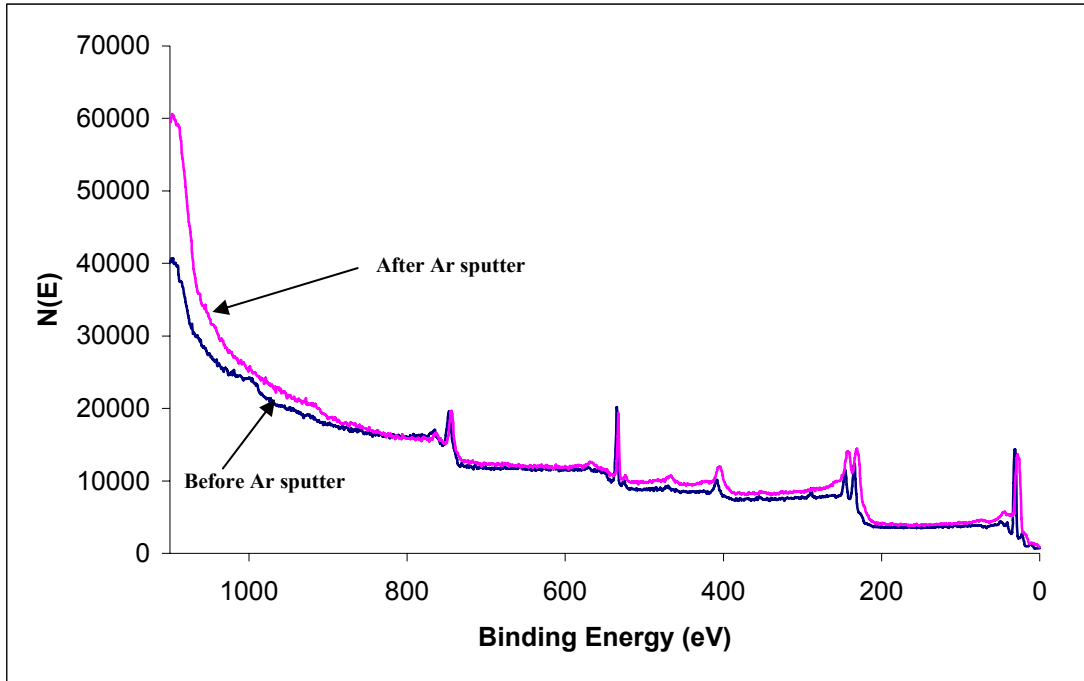


Figure 12: XPS scan of Ta<sub>2</sub>O<sub>5</sub> film (calcined in O<sub>2</sub> at 1000°C)

	Binding energy	Atomic concentration before Ar sputter	Atomic Concentration after Ar sputter
<b>O 1s</b>	531 eV	63.7 %	60.4 %
<b>C 1s</b>	285 eV	13.8 %	0.9 %
<b>Ta 4f<sub>5/2</sub></b>	24 eV	22.6 %	38.7 %

Figure 13: XPS table of assignment

**X-ray diffraction analysis:** Identification of the phases of the resulting oxide film was performed via XRD on a Rigaku DMAX<sup>®</sup> XRD system with Cu (K $\alpha$ ) radiation. (fig. 14)

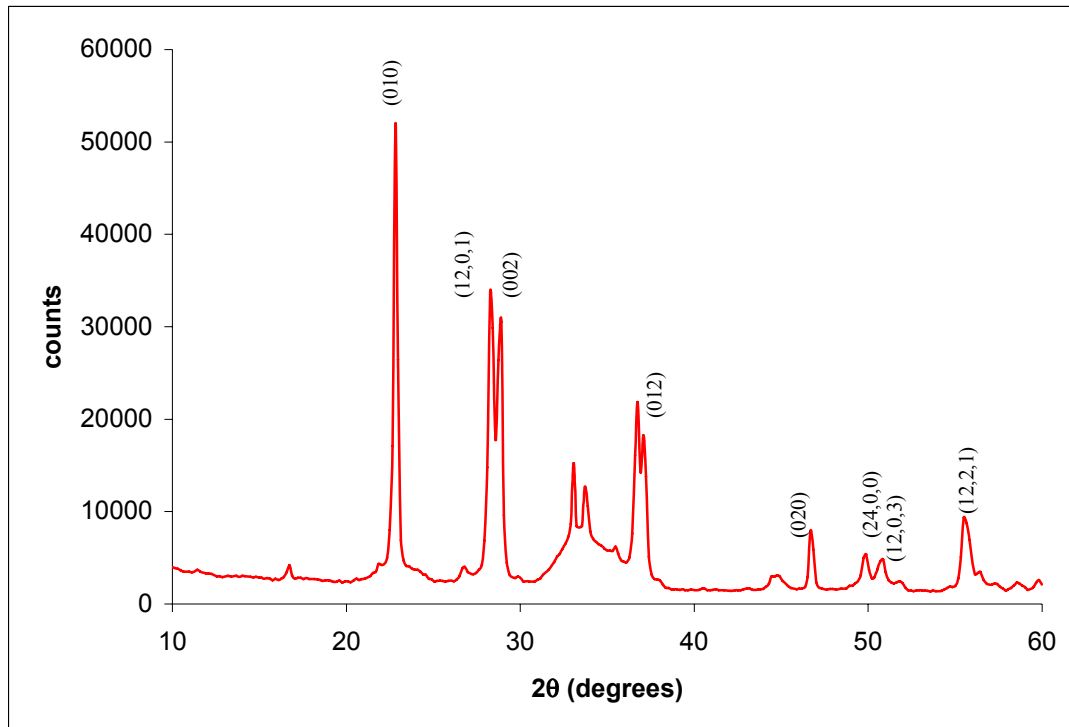


Figure 14: XRD spectrum of Ta<sub>2</sub>O<sub>5</sub> film (calcined in O<sub>2</sub> at 1000°C)

**TGA analysis:** Thermogravimetric analysis was performed to elucidate the change in physical properties that occurs through the calcination cycle to yield the final oxide film. Analysis was performed on a TGA7/DSC7 Perkin Elmer<sup>®</sup> system. Samples were heated from ambient temperature to 1000°C at a rate of 1.6°C/min under a steady O<sub>2</sub> flow of 20cm<sup>3</sup>/min and finally held at 1000°C for 10 hours. (fig. 15)

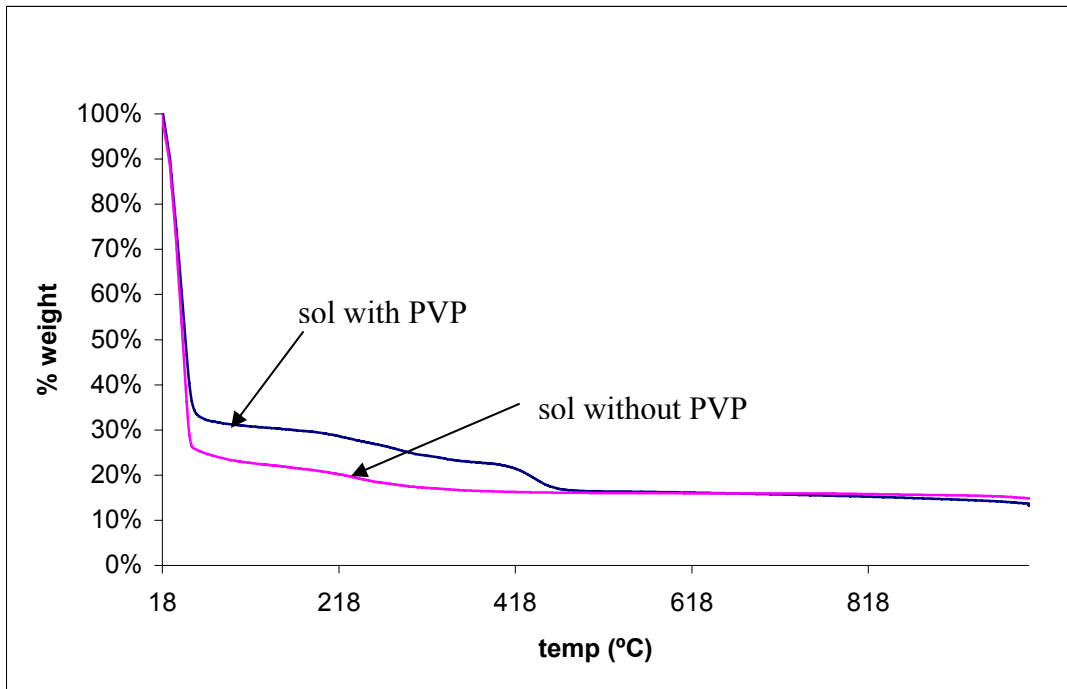


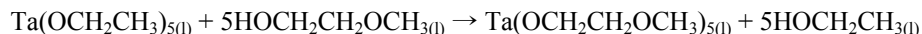
Figure 15: TGA analysis of Ta<sub>2</sub>O<sub>5</sub> sol precursor with PVP and without PVP

## Discussion

The <sup>1</sup>H spectrum is of a characteristic 2-methoxyethoxide type of coordination<sup>30, 31</sup> (fig. 7 & 8). The triplet at 3.7 ppm on the <sup>1</sup>H spectrum corresponds to a CH<sub>2</sub> hydrogen of a carbon bound to another CH<sub>2</sub> whose hydrogen signal appears at about 3.48 ppm (triplet) and is bound to an O atom.<sup>30</sup> The singlet at 3.38 ppm corresponds to CH<sub>3</sub> hydrogen bound to an oxygen atom. The <sup>13</sup>C spectrum confirms the above coordination with the methyl carbon at 58.8 ppm, the oxygen bonded CH<sub>2</sub> carbon at 73.6 ppm and the adjacent CH<sub>2</sub> carbon at 61.7 ppm (fig. 9).<sup>30</sup> The broad region in the <sup>1</sup>H appearing around 2.7 ppm is also observed in a sample of the original Ta(OCH<sub>2</sub>CH<sub>3</sub>)<sub>5</sub> in the same NMR standard as used above. NMR spectra of samples with CaSO<sub>4</sub> pellet yielded identical spectra to the ones above, thus showing that the broad band is not due to water present in the sample. The source of this band is still under investigation.

The NMR spectra suggest that the ethoxide ligands around the Ta metal center are exchanged for the -OCH<sub>2</sub>CH<sub>2</sub>OCH<sub>3</sub> ligand. There is no trace of any ethoxide/ethanol, hence we can conclude that the exchanged ethoxide ligands are removed as ethanol during the vacuum evaporation stage of synthesis. The coordination of the Ta cannot be

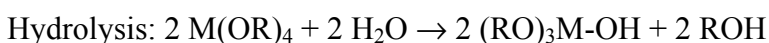
deciphered from this analysis, but the suggested product is  $\text{Ta}(\text{OCH}_2\text{CH}_2\text{OCH}_3)_5$  via the reaction:<sup>4, 9, 32-34</sup>



Alternatively, the NMR signature could be purely from the solvent and the Ta metal center could be immobilized via Ta-O bonds to the PVP molecule.<sup>21</sup> Proton NMR spectrum of 2-methoxyethanol yields a quartet centered at 3.7 ppm. The occurrence of a triplet for this sample suggests the existence of deprotonated OH group possibly due to extensive hydrogen bonding. Presence of the Ta-O and Ta-O-C bonds is verified by the FTIR bands  $< 1000 \text{ cm}^{-1}$ . Band assignments are listed in fig. 4.

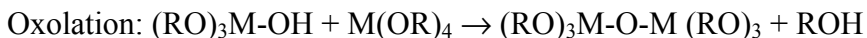
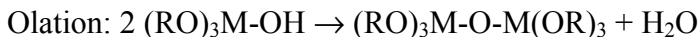
Analysis of sols at different points in time via both NMR and FTIR does not show any change in chemical composition of the sol (fig. 5 & 6). This suggests that the difference observed in film thickness and microstructure from sols of different age is either a physical effect, namely the binder interaction with the  $\text{Ta}(\text{OCH}_2\text{CH}_2\text{OCH}_3)_{5(l)}$  (or the Ta metal center) and solvent, or a modification of the binder molecular chain arrangement. PVP is capable of hydrogen bonding via the C=O functional group, though findings in this work suggest that there could be more than H-bonding taking place. Given the large size of the PVP molecule chains, it is most likely that the freshly synthesized sols have highly crosslinked PVP molecules. The sol precursor exhibits bands at  $1603$  and  $1540 \text{ cm}^{-1}$  that are absent from the control and comparison spectra. These bands fall in the regions where non cyclic amino and amido modes are expected (hydroxyamic C=O ( $1600$ - $1800 \text{ cm}^{-1}$ ) and C-N stretching ( $1525$ - $1575 \text{ cm}^{-1}$ ) bands, amide N-H in plane bending ( $1515$ - $1570 \text{ cm}^{-1}$ ) and primary alkylamic  $\text{NH}_2$  scissoring ( $1610$ - $1650$ ))<sup>26</sup>. This suggests that there could be an alteration of the polymeric structure that is undetectable by NMR experiments. This is supported by the microstructure observed in the green films resulting from fresh sols (fig. 11). The polycondensed oxide particles are about  $822 \text{ nm}$  in diameter (fig. 11(a)). As time goes by, there is by further polycondensation of the oxide network giving larger particle sizes in the films derived from sols subjected to greater ageing ( $933 \text{ nm}$ ) (fig. 11(b)). SEM micrographs of green films from aged sols show particle sizes of about  $1.11 \mu\text{m}$  diameter (fig. 11(c)).

General polycondensation sequence of reaction is as follows:<sup>4, 33, 34</sup>





Subsequent condensation reactions involving the hydroxyl groups yield networks composed of inorganic oxide (M-O-M) linkages.



This is also supported by the thinner, denser films resulting from aged sols in comparison to fresh sols subjected to identical deposition spin rate, implying a less crosslinked matrix (fig. 10) due to growth of M—O—M particles.

Acetylacetone has been observed to not only slow down the rate of hydrolysis and polycondensation but also to significantly influence the morphology and crystallinity of the final product of the sol gel synthesis.<sup>35, 36</sup> In this synthesis, acetylacetone is seen as likely to cause crosslinking of PVP molecules. The spherical polycondensed oxide particles are not present in control sols (without acetylacetone) until the sol ages and turns turbid as seen in the SEM images (fig. 11 (d)-(f)). This is further evidence as to the open network that allows for greater penetration of moisture in the crosslinked sol upon exposure to ambient conditions, resulting in greater hydrolysis. Given that the green films without acetylacetone are denser than the ones with acetylacetone, and that the FTIR data taken over time does not show any changes in the relative hydrogen bonding peaks it is less probable that the extensive pore structure in the latter is due to pure hydrogen bonding.

TGA results show an initial drop in mass up to 50°C attributed to solvent evaporation (fig. 15). Between 60°C and 500°C there is a change in the rate of decrease in % weight, with the PVP assisted sample showing a slower rate of change than the sample without PVP. There is a significant increase in the rate of decrease of % weight at 450 °C, which is attributable to a change in structure from amorphous to orthorhombic Ta<sub>2</sub>O<sub>5</sub>. Beyond 500°C the rate of change in % weight is relatively similar for both samples. This supports the hypothesis that the presence of PVP serves to relieve tensile stress within the film upon thermal treatment up to about 500°C when all the binder is pyrolysed.<sup>22, 28</sup> The slower rate of decrease in % weight signifies slower change in the film microstructure, a plasticity that allows differential expansion between the film particles and substrate with minimal or no cracking of the film.

XPS data reveals 13.8% carbon content that is reduced to 0.9% upon sputtering with argon, confirming ambient contamination as the carbon source. This shows that the removal of PVP is complete and there is negligible residual carbon. The Ta:O ratio confirms atomic coordination as Ta<sub>2</sub>O<sub>5</sub> (fig. 12 & 13).

XRD pattern identifies the film obtained as orthorhombic Ta<sub>2</sub>O<sub>5</sub>. The spectrum matches ICSD card # 97-004-7493 with Miller indices labeled in fig. 14.

## Conclusion

PVP has been shown as an effective binder material in the sol gel synthesis of thick Ta<sub>2</sub>O<sub>5</sub> films for high temperature applications. This study was undertaken to investigate the effect of PVP binder in the sol precursor via NMR, FTIR, TGA, XPS, SEM, and XRD analytical tools. It has been reported that the type of Ta<sub>2</sub>O<sub>5</sub> films obtained from sols of different ages varies in thickness and microstructure, suggesting that there was a progressive change occurring in the composition of the sol precursor with time. It was found that incorporation of PVP in the presence of acetylacetonone results in extensive crosslinking of the sol matrix. This serves to relieve tensile stresses generated in the film during solvent removal and thermal treatment due to thermal mismatch between the deposited film and the substrate. The resulting films are found to be stable and crack free. With time, there is continued polycondensation of the Ta—O—Ta network yielding denser, thinner films with particles of larger diameter.

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